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COMMUNICATION

Guided formation of sub-5 nm interstitial gaps between plasmonic nanodisks

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To achieve a reliable formation of a surface-enhanced Raman scattering (SERS) sensor with evenly distributed hot spots on a wafer scale substrate, we propose a hybrid approach combining a physical nanolithography for preparing Au nanodisks and a chemical Au reduction for growing them. During the chemical growth, the interstitial distance between the nanodisks decreased from 60 nm to sub-5 nm. The resulting patterns of the nanogap-rich Au nanodisks successfully enhance the SERS signal, and its intensity map shows only a 5 % or less signal variation on the entire sample.

Introduction

Surface-enhanced Raman scattering (SERS) enables a highly-sensitive, non-destructive, and multiplexing molecular detection and has become a powerful tool to detect biomolecules, pharmaceuticals and environmental toxins.\textsuperscript{1,3} Because surface-plasmon-induced electric-field enhancement is a key factor in the signal enhancement mechanism in SERS,\textsuperscript{4,5} a reliable formation of a “hot spot”, where the electromagnetic field enhanced by surface plasmon resonance can reach its highest value, is a prerequisite for practical uses of SERS. Hence, many technical approaches have been proposed for a reproducible SERS substrate with a high density of hot spots, one such approach being the lithography-based top-down fabrication.\textsuperscript{6,10} Such electron-beam lithography (EBL) allows the production of a well-controlled plasmonic nanostructure with customized-size, shape and spacing.\textsuperscript{11,12} However, the proximity effect originating from the scattering of incident electrons\textsuperscript{13,14} makes it difficult to control the interstitial distance between neighboring nanostructures under 5 nm, a size-domain that is particularly attractive for the plasmonic hot-spots. Bottom-up approaches, on the other hand, such as self- or guided-assembly of nanoparticles, are easier to reduce the distance between the metallic nanoparticles down to 1 nm or less.\textsuperscript{17,18} Considering the location, density, and signal enhancement factor of the hot spots, however, bottom-up methods are usually accompanied by loss of reproducibility.\textsuperscript{19,20} There were a little attempts to utilizing the advantages of both approaches. Gopinath \textit{et al}, tried to combine EBL with chemical growth, but randomly distributed small nanoparticles on aperiodic nanostructure reduce reproducibility because of different gap sizes.\textsuperscript{21}

Here, we report a top-down and bottom-up combined method for the formation of sub-5 nm interstitial gaps in a wafer scale. In the proposed method, the array of Au nanodisks, which were patterned by nanoimprint lithography, functions as a preferential site for reducing Au ions in a solution mixture of hydrogen tetrachloroaurate(III) trihydrate (HAuCl\textsubscript{4}·3H\textsubscript{2}O) and hydroxylamine hydrochloride (NH\textsubscript{2}OH·HCl). Therefore, the interstitial distance between the Au nanodisks could be reduced during the Au reduction time from initially 60 nm to sub-5 nm. The evenly distributed sub-5 nm interstitial gaps, namely hot spots, on a whole sample were successfully verified by the analyses of molecular Raman signals and by numerical electromagnetic simulations.

Results and discussion

In order to prepare the array of sub-5 nm gaps, we used a top-down and bottom-up combined method, as illustrated in Fig. 1a. The top-down steps of the nanoimprint lithography (NIL) and Au evaporation offer the distinct benefits of nanoscale resolution, reproducible patter
Because NH₄OH·HCl is used as a reductant of HAuCl₄, high ratio of NH₄OH·HCl to HAuCl₄ speeds up the reduction and narrows down the experimental window. In our experiments, the mixture ratio of 0.3 mM HAuCl₄·3H₂O (99.9 %) 5 mL and 0.4 mM NH₄OH·HCl (99 %) 5 mL was optimum. Moreover, the growth rate difference of Au on top of the nanodisks (~150-nm- increase in height for 20 min) and its sidewall surface (~60-nm-increase in diameter for 20 min) is also quite similar to the non-conformal thin-film growth on a non-planar surface. Fig. 1d clearly demonstrates the evenly enlarged Au nanodisks, and consequently the narrowed interstitial gap between the nanodisks. During the reduction time of 20 min, the average diameter of the Au nanodisks increased from 180 nm to 237 nm, and the interstitial gap was successfully reduced to 3 nm with 2.9 nm of its standard deviation. The gap distances were evaluated by the statistical analysis protocol proposed for measuring the size of nanoparticles in SEM.

To assess the effect of the prepared nanogap structure on SERS enhancement, a three dimensional finite-difference time-domain (FDTD) simulation was carried out using commercial software (Lumerical FDTD solution 8.9). For a proper simulation of the plasmonic structure, the SEM images of the nanodisks in Fig. 1b-d were imported and placed on the infinite Si substrate. The modeled structures were illuminated from the top by a linearly polarized plane wave with a wavelength of 633 nm, the wavelength employed for SERS experiments. Fig. S1 in supporting information also shows that the all modeled structures are activated most strongly at a wavelength between 600 nm and 700 nm. Because the electric field enhancement from a localized surface plasmon resonance is known to be the major mechanism for SERS, two dimensional maps visualizing the enhanced electric fields of |E/E₀|², where E₀ and E are the amplitudes of the incident and enhanced electric fields, respectively, are shown in Fig. 2. The red-colored regions in the
maps clearly show that the local electric field is strongly enhanced at the interstitial gaps between the nanodisks and that field enhancement increases with the Au reduction time. Quantitatively, the maximum and the pixel-weighted sum of $|E/E_0|^4$, which were calculated from each field map in Fig. 2a-c and displayed in Fig. 2d, e, increase respectively about 8000 times and 300 times by decreasing the gap distance from 60 nm to sub-5 nm.

![Image](image-url)

**Fig. 3** (a) Representative SERS spectra of RITC molecules adsorbed on three different plasmonic nanostructures in Fig. 1a-c. All spectrum baselines are not corrected. (b) (Bar graph) The experimentally measured SERS intensities of major peaks in Fig. 3a and (red square) the calculated sum of $|E/E_0|^4$ values in Fig. 2e. (c) Two-dimensional intensity map of SERS intensity (1647.3 cm$^{-1}$) obtained from the 1-μM RITC treated Au nanodisks with sub-5 nm interstitial gaps. (d) SERS intensities of major peaks and their standard deviations analyzed from the entire area of the Fig. 3c.

The enhancement of the Raman signal depending on the interstitial distance between the Au nanodisks was experimentally demonstrated. Three samples of three different kinds of Au nanodisks in Fig. 1b-d were incubated in 10$^{-6}$ M concentrated Rhodamine B isothiocyanate (RITC) solution for 1 hour and rinsed with deionized water. Fig. 3a shows the representative Raman spectra of RITC molecules adsorbed on the three different nanostructures, and it is clear that the enhancement of SERS intensity increases with the Au reduction time. For a comparison of the simulated and experimental results, Raman intensities of several major peaks in Fig. 3a were plotted in Fig. 3b with the sum of $|E/E_0|^4$ values in Fig. 2e, which are known to be proportional to the average intensities of the SERS signal.\(^{24}\) If we consider the detection limit (three times of noise level) of our experiments, there should be a minimum of two orders of magnitude difference between the Raman intensities from the two samples of the initially patterned nanodisks and the final enlarged nanodisks. Therefore, these experimental results align reasonably well with the 300-fold-difference in the calculated sum values of $|E/E_0|^4$. The experimental value for enhancement factor (EF) was estimated to be about 1.5 x 10$^5$ (Fig. S3 and related text). Because the estimated diameter of the laser beam is about 858 nm and the beam size is correlated to about 10 nanodisks and their neighboring nanogaps, the experimentally assessed EF is its area-averaged value. The EF of our SERS substrate is rather low compared to the EF values reported in many previous studies including the substrate fabricated by nanosphere lithography. However, the study on the site distribution of SERS enhancement from Ag thin films on self-assembled nanospheres shows that the hottest sites (EF > 10$^9$) account for only 0.006% of the total.\(^{26}\) The main advantage of our SERS substrate is its reliable performance based on evenly distributed hot spots as demonstrated below.

Finally, a two dimensional distribution of the Raman signal (1647.3 cm$^{-1}$) was mapped in Fig. 3c in order to verify the uniformity of our SERS substrate, the array of Au nanodisks with the interstitial nanogaps. The overall appearance of the SERS map in Fig. 3c shows the homogeneously enhanced Raman signal from the entire area, and the statistics of the Raman intensities in Fig. 3d shows only about 5% of standard deviation. Zheng et al. evaluated a signal variation of the commercially available Klarite SERS substrate showed a 45% spot to spot variation.\(^{27}\) So far as we know, the most reproducible SERS substrate was a silver nanocluster made from copolymer micelles which showed around a 5% signal variation.\(^{28}\) Compared to the signals observed in previous reports and from commercial SERS substrate, the physically patterned and chemically enlarged Au disks have good SERS signal reproducibility for a large area. Moreover, the almost identical SERS intensities in Fig. 3b and d were actually obtained from two different samples fabricated from two different batches but are almost identical, which suggests batch-to-batch reproducibility.

**Conclusions**

We have presented a reliable and straightforward method for fabricating SERS substrates by combining top-down and bottom-up approaches. From the physical process, the overall shapes and dimensions of the Au nanodisks are defined by nanoimprint lithography and thin film deposition, and the interstitial distances between the nanodisks are controlled by the chemical process of Au reduction. The proposed method allowed us to form the array of Au nanodisks with sub-5 nm gaps, and concomitantly to enhance SERS activities which were confirmed by SERS experiments and numerical simulation. Because both the imprint-based nanopatterning and Au-reduction-chemistry-based pattern modifying can be scaled up to a wafer scale, and the presented results demonstrate a highly sensitive and spatially uniform molecular detection, we expect that our nanogap-controlled Au nanodisk array can be used as a practical SERS substrate.

**Experimental section**

**Preparation of the array of Au nanodisks with sub-5 nm gap**

Fig. 1a outlines the overall process used in this study. First, for the formation of the Au nanodisks, the spin-coated PMMA (mr-1 PMMA, Microresist technology) / PMGI (PMGI SF3, Microem) bilayer on a Si wafer was subjected to thermal nanoimprinting at 200 °C under a pressure of 30 bar for 5 min. After nanoimprinting, the residual PMMA layer was etched by O$_2$ plasma, and the sample was immersed in a commercial wet chemical developer (AZ MIF300, AZ electronic materials) for 3 to form an undercut profile in the PMGI resist. Next, a 3 nm Ti adhesion layer followed by a 50 nm Au layer was deposited using thermal evaporation at a pressure of 2.0 x 10$^{-6}$ Torr. After removal of the spin-coated polymers by AZ MIF 300 and rigorous sample cleaning by ethanol and water, the arrays of Au nanodisks were immersed for 2 and 20 min in mixtures of 0.3 mM HAuCl$_4$·3H$_2$O (99.9 %) 5 mL and 0.4 mM NH$_3$OH (99 %) 5 mL. Then, the enlarged Au nanodisks were cleaned with deionized water (DW), and dried with nitrogen gas. Finally, the samples were
exposed to UV-ozone was adopted to remove possible contamination for 1 hr.

**Instrumentation and characterization**

For SERS measurements, the samples of the Au nanodisks were immersed in a RTIC aqueous solution with a concentration of 10^{-6} M for 1 hr, and rinsed thoroughly with deionized water to remove non-specifically bound 6Rb molecules, and then dried with nitrogen gas. UV/O_3 exposure was performed using a commercial ozone cleaning system (PSD-UV, Novascan Technologies, Ames, IA, USA). The SERS measurements were performed using a laboratory-made micro-Raman system based on a 633 nm diode laser and a 50x objective lens with a thermoelectrically cooled CCD detector (iDUS 401, ANDOR). The laser power was 0.25 mW after passing through the lens and the focused spot size was estimated to be as 1.4 μm (≈ 122 λ/NA, with NA = numerical aperture = 0.55). The SERS spectra from a single point were obtained from with 3 s integration time. Sample surfaces were also mapped over 16 μm wide square frames with a pixel size of 1 μm × 1 μm and an accumulation time of 10 s pixel^{-1}.

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